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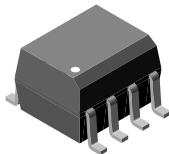
sales@integrated-circuit.com



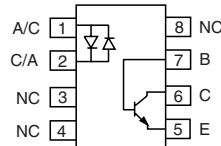
IL256AT

Vishay Semiconductors

Optocoupler, Phototransistor Output, AC Input, with Base Connection



H179025



FEATURES

- Guaranteed CTR symmetry, 2:1 maximum
- Bidirectional AC input industry standard SOIC-8 Surface mountable package
- Isolation test voltage, 4000 V_{RMS}
- Standard lead spacing, 0.05"
- Available only on tape and reel (conform to EIA standard RS481A)
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS COMPLIANT

DESCRIPTION

The IL256AT is an AC input phototransistor optocoupler. The device consists of two infrared emitters connected in reverse parallel and coupled to a silicon NPN phototransistor detector. These circuit elements are constructed with a standard SOIC-8 foot print. The product is well suited for telecom applications such as ring detection or off/on hook status, given its bidirectional LED input and guaranteed current transfer ratio (CTR) minimum of 20 % at I_F = 10 mA.

APPLICATIONS

- Telecom applications ring detection

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- CUL - file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-2 (VDE 0884) available with option 1

ORDER INFORMATION

| PART | REMARKS |
|---------|-----------------------------------|
| IL256AT | CTR > 20 %, tape and reel, SOIC-8 |

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
|--|----------------|-------------------|---------------|------------------|
| INPUT | | | | |
| Forward continuous current | | I _F | 60 | mA |
| Power dissipation | | P _{diss} | 90 | mW |
| Derate linearly from 25 °C | | | 0.8 | mW/°C |
| OUTPUT | | | | |
| Collector-emitter breakdown voltage | | BV _{CEO} | 30 | V |
| Emitter-collector breakdown voltage | | BV _{ECO} | 5 | V |
| Collector-base breakdown voltage | | BV _{CBO} | 70 | V |
| Power dissipation | | P _{diss} | 150 | mW |
| Derate linearly from 25 °C | | | 2.0 | mW/°C |
| COUPLER | | | | |
| Isolation voltage, input to output | | V _{ISO} | 4000 | V _{RMS} |
| Total package dissipation (LED and detector) | | P _{tot} | 240 | mW |
| Derate linearly from 25 °C | | | 3.2 | mW/°C |
| Storage temperature | | T _{stg} | - 55 to + 150 | °C |
| Operating temperature | | T _{amb} | - 55 to + 100 | °C |
| Soldering time at 260 °C | | | 10 | s |

Note

T_{amb} = 25 °C, unless otherwise specified.
 Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

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| ELECTRICAL CHARACTERISTICS | | | | | | |
|---------------------------------------|---|-------------|------|------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| INPUT | | | | | | |
| Forward voltage | $I_F = \pm 10 \text{ mA}$ | V_F | | 1.2 | 1.5 | V |
| OUTPUT | | | | | | |
| Collector emitter breakdown voltage | $I_C = 1.0 \text{ mA}$ | BV_{CEO} | 30 | 50 | | V |
| Emitter collector breakdown voltage | $I_E = 100 \mu\text{A}$ | BV_{ECO} | 5 | 10 | | V |
| Collector base breakdown voltage | $I_C = 100 \mu\text{A}$ | BV_{CBO} | 70 | 90 | | V |
| Collector emitter leakage current | $V_{CE} = 10 \text{ V}$ | I_{CEO} | | 5 | 50 | nA |
| COUPLER | | | | | | |
| Saturation voltage, collector emitter | $I_F = 16 \text{ mA}, I_C = 2 \text{ mA}$ | V_{CEsat} | | | 0.4 | V |

Note

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified. Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| CURRENT TRANSFER RATIO | | | | | | |
|--|---|------------|------|------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| DC current transfer ratio | $I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$ | CTR_{DC} | 20 | | | % |
| Symmetry (CTR at + 10 mA)/(CTR at -10 mA) | | | 0.5 | 1 | 2 | |

| SAFETY AND INSULATION RATINGS | | | | | | |
|---|------------------------|--------|------|-----------|------|------------------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Climatic classification (according to IEC 68 part 1) | | | | 55/100/21 | | |
| Comparative tracking index | | CTI | 175 | | 399 | |
| V_{IOTM} | | | 6000 | | | V |
| V_{IORM} | | | 560 | | | V |
| PSO | | | | | 350 | mW |
| ISI | | | | | 150 | mA |
| TSI | | | | | 165 | $^\circ\text{C}$ |
| Creepage distance | | | 4 | | | mm |
| Clearance distance | | | 4 | | | mm |
| Insulation thickness, reinforced rated | per IEC 60950 2.10.5.1 | | 0.2 | | | mm |

Note

As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

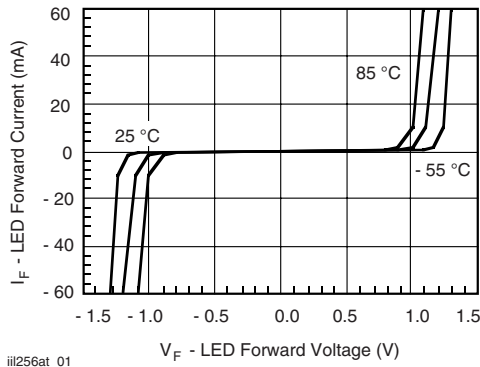


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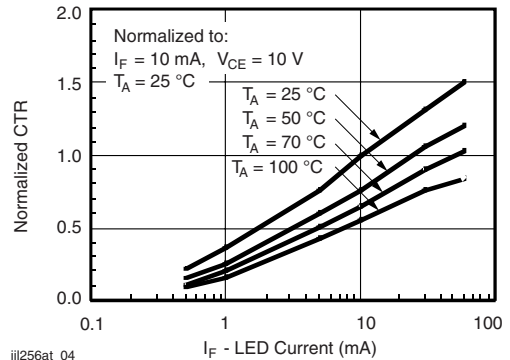
TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified



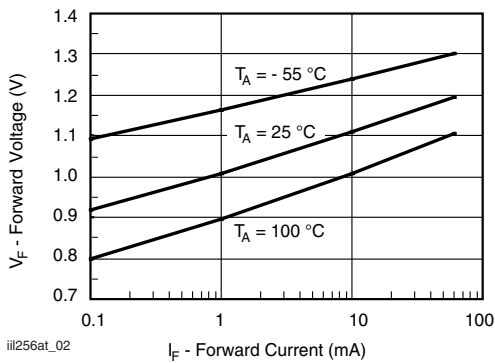
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Fig. 1 - LED Forward Current vs. Forward Voltage



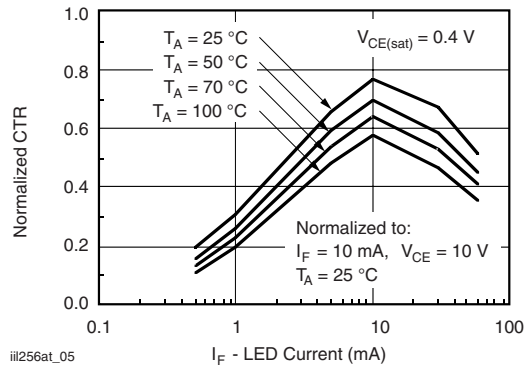
iii256at_04

Fig. 4 - Normalized CTR vs. I_F and T_{amb}



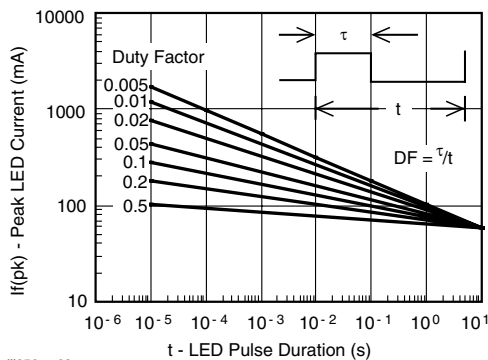
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Fig. 2 - Forward Voltage vs. Forward Current



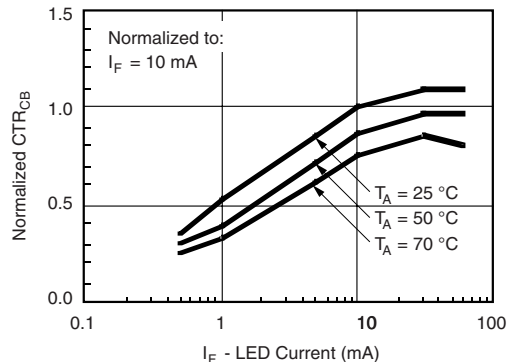
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Fig. 5 - Normalized Saturated CTR



iii256at_03

Fig. 3 - Peak LED Current vs. Duty Factor, Tau



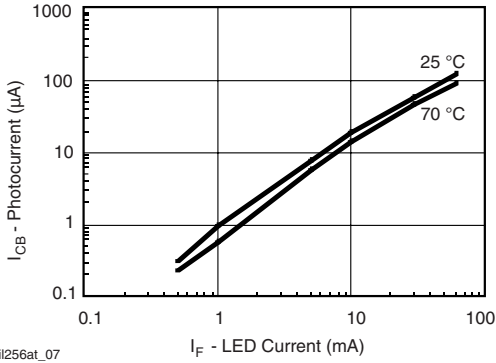
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Fig. 6 - Normalized CTR_{cb}

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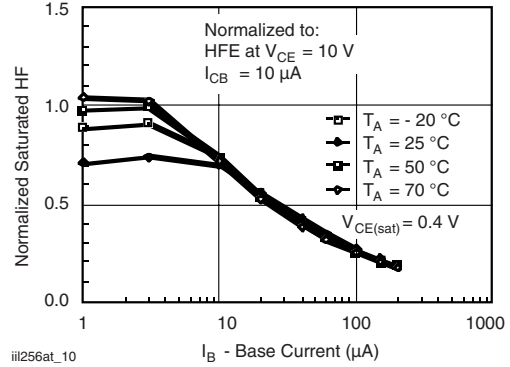


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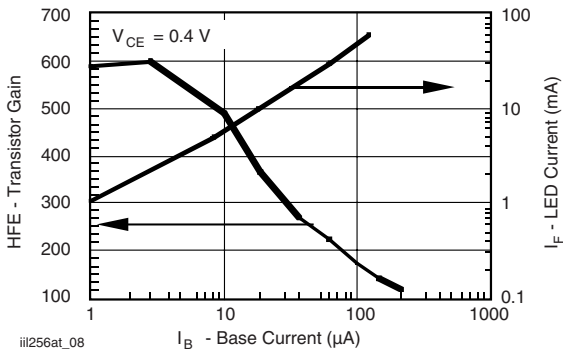
iii256at_07

Fig. 7 - Photocurrent vs. LED Current



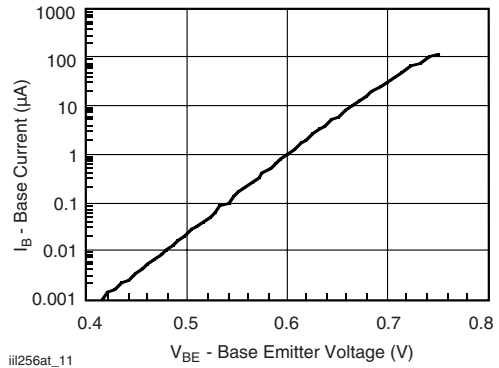
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Fig. 10 - Normalized Saturated h_{FE} vs. Base Current



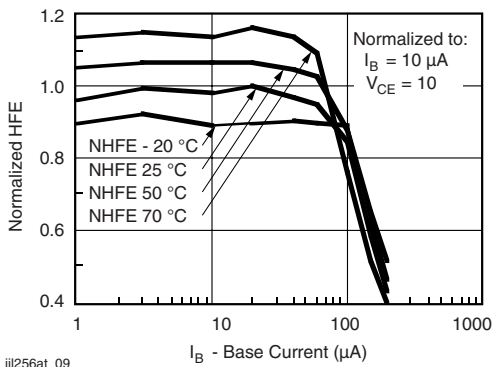
iii256at_08

Fig. 8 - Base Current vs. I_F and h_{FE}



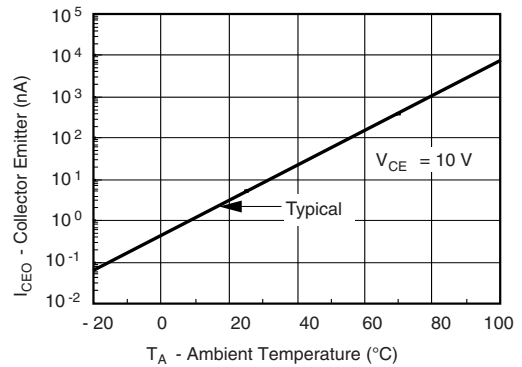
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Fig. 11 - Base Emitter Voltage vs. Base Current



iii256at_09

Fig. 9 - Normalized h_{FE} vs. Base Current and Temp.



iii256at_12

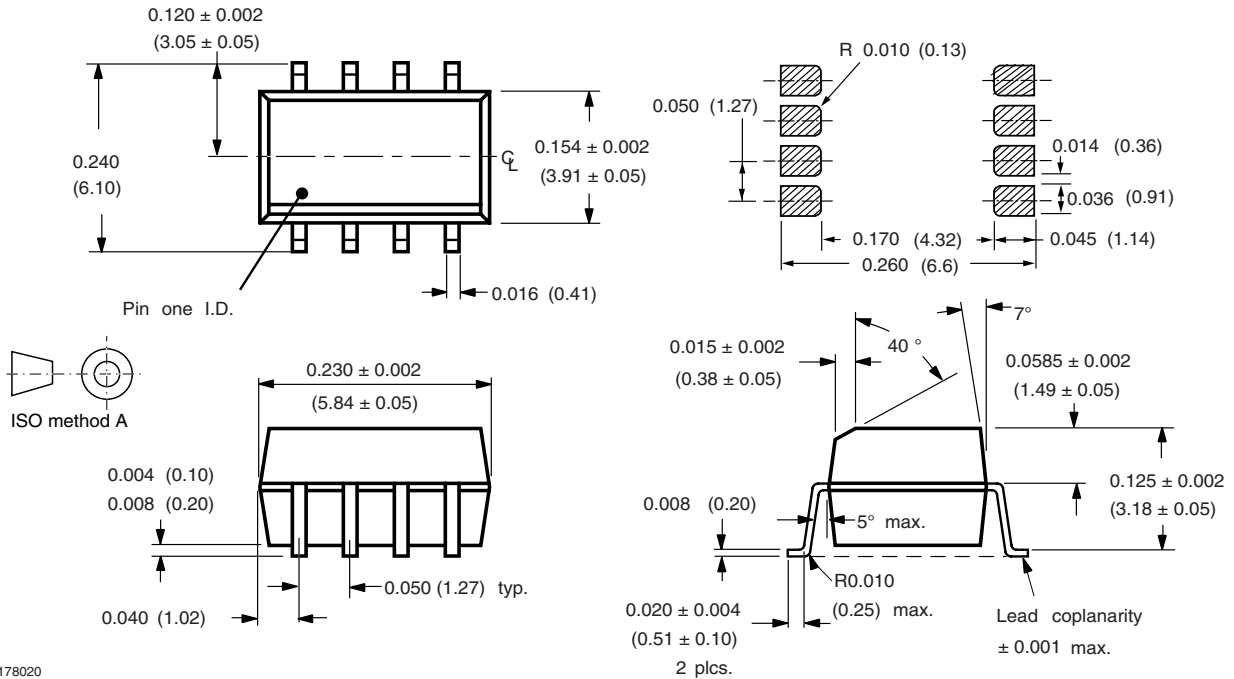
Fig. 12 - Collector-Emitter Leakage Current vs. Temp.



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PACKAGE DIMENSIONS in inches (millimeters)



i178020

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OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

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